	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e n	r D e f i n	Error
1	BRS	1	metal and metal near mask\$	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/09/10 18:17			0
2	BRS	4	high adj K with metal and metal with mask\$ and mask\$ with sacrificial	TBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:20			0
3	BRS	1 1	i	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:20			0
4	BRS	16	high adj K with metal and metal with mask\$ and conformal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:29		-	0
5	BRS	39	metal and metal with mask\$ and protect\$ and wet with etch\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:38			0
6	BRS	91	dielectric with metal and metal with mask\$ and wet near etch\$ with dielectric and (dry or plasma) near etch\$ with metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:55			0
7	BRS	6	6300202.URPN.	USPAT	2004/09/10 18:48			0
8	BRS	2	("5885877"   "6300202").PN.	USPAT	2004/09/10 18:50			0
9	BRS	30	5885877.URPN.	USPAT	2004/09/10 18:50			0

	Тур е	Hi ts	Search Text	DBs	Time Stamp	o m m e n	e f i	Errors
10	BRS		dielectric with metal and metal with mask\$ and wet near etch\$ with (high near K near dielectric or metal near oxide)		2004/09/10 19:00			0
111	BRS	65	dielectric with metal and metal with mask\$ and mask with (sidewall near spacer or conformal\$ or protect\$ or sacrificial\$) and wet with etch\$ with (dielectric or metal near oxide) and etch\$ with metal and stack\$	JPO; DERWENT; IBM_TDB	2004/09/11 17:51			0
12	BRS	10	, ,	USPAT; US-PGPUB; EPO;	2004/09/11 17:57			0
13	BRS	2	•	USPAT; US-PGPUB; EPO;	2004/09/11 18:00			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m e n	D e f i	Erro
14	BRS	i	dielectric with metal and mask\$ near metal and sidewall with (spacer or protect\$) with mask\$		2004/09/11 18:06			0
15	BRS	32	etch\$ with metal with stack and sidewall with (spacer or protect\$) with mask\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:17			0
16	BRS		MIDIOCIFIC AND	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:21			0
17	BRS	96	(dielectric or oxide) with substrate and metal with (dielectric or oxide) and mask\$ with metal and (sidewall or spacer or protect\$) with mask\$ and high adj k	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:24			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	Comments	D e f i	Errors
18	BRS	24	(dielectric or oxide) with substrate and metal with (dielectric or oxide) and mask\$ with metal and (sidewall or spacer or protect\$) with mask\$ and high adj k and mask\$ with polysilicon	JPO; DERWENT; IBM_TDB	2004/09/11 18:38			0
19	BRS	12	(dielectric or oxide) with substrate and metal with (dielectric or oxide) and mask\$ with metal and side\$6 with mask\$ and high adj k and mask\$ with polysilicon and gate near metal	JPO; DERWENT; IBM_TDB	2004/09/11 18:43			0
20	BRS		gate near metal and mask\$ with metal and (cap\$6 or protect\$ or sacrificial) with mask\$ with side\$6 and mask\$ with polysilicon	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 19:21			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e n	D e f i	E
21	BRS	2	gate near metal and mask\$ near (metal or gate) and high adj k with gate near dielectric and (cap\$6 or protect\$ or sacrificial) with mask\$ with side\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 19:25			О
22	BRS	3	gate near metal and high adj k with gate near dielectric and (cap\$6 or protect\$ or sacrificial) with mask\$ with side\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 19:26			0
23	BRS	34	gate near metal and high adj k with gate near dielectric and mask\$ with side\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 20:36			0
24	BRS	59	gate near metal and high adj k with gate near dielectric and mask\$ and work adj function	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:05			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e n	ErrorDefinitio	r r o r
25	BRS		gate near metal and gate near dielectric and mask\$ near (metal or gate) and work adj function and (protect\$ or sacrificial or conformal) with metal with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:13			Ο
26	BRS	21	gate near metal with gate near dielectric and mask\$ near (metal or gate) and work adj function	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:20			0
27	BRS		etch\$ with gate near metal same mask\$ near (metal or gate) and work adj function and layer with (metal or gate) with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:27			0
28	BRS	11	etch\$ with gate near metal and mask\$ near (metal or gate) and work adj function and layer with (metal or gate) with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:28			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e n	ErrorDefinitio	Error
29	BRS	1		JPO; DERWENT;	2004/09/11 21:39			Ο
30	BRS	3	and work adj	JPO; DERWENT;	2004/09/11 21:32			0
31	BRS	6	(metal or gate) and sacrificial with (metal or gate or mask)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:33			0
32	BRS		etch\$ with gate near metal same mask\$ near (metal or gate) and protect\$ with (metal or gate) with mask		2004/09/11 21:34			0
33	BRS	1	etch\$ with gate same mask\$ near gate and sacrificial with metal with mask		2004/09/11 21:41			0
34	BRS	2	etch\$ and gate near stack\$ same mask\$ near gate and sacrificial with gate with mask	US-PGPUB; EPO;	2004/09/11 21:45			0

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	Typ e	Hi ts	Search Text	DBs	Time Stamp	m m e n	ErrorDefinitio	Error
35	BRS	1	etch\$ near gate same mask\$ near gate and work adj function and sacrificial with gate with mask	US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:47			0
36	BRS	3	etch\$ near gate same mask\$ near gate and sacrificial with gate with mask	TDO DEDMENT.	2004/09/11			0
37	IS& R	2	("6063698").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:52			0
38	IS& R	2	("6184072").PN.	፱ <b>ይ</b> ፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟፟	2004/09/11 21:53			0
39	IS& R	2	("6420279").PN.	ਚ <b>ይሥ</b> ሏቸ <b>ጋ</b> Β US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:53			0
40	IS& R	2		世島坪A平DB US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:54			0
41	IS& R	2	("6514828").PN.	世島野人平身B US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:54			0
42	IS& R	2	("6544906").PN.	世島神入平身B US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:54			0
43	IS& R	2	("6617209").PN.	JPO; DERWENT;	2004/09/11 21:55			0
44	IS& R	2	("6620713").PN.	世島野A平身B US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:55			0
45	IS& R	2	("6689675").PN.	世島野 <u>み</u> 罪ゆB US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:56			0
46	IS& R	2	("6696345").PN.	世島神A平DB US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:57			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e	r D e f i	E r o r
47	IS& R	2	i .	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 21:57			0
48	IS& R	0	(2002/0197790).C CLS.	也另种A平身B US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 22:00			0
49	IS& R	2	("20020197790"). PN.	也多姓人平身B US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 22:01			0
50	IS& R	2	("20030032303"). PN.	古 <b>5坪</b> A平 <b>)</b> B US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 22:01			0
51	IS& R	2	("20030045080"). PN.	世 <b>島坪<u>入</u>平</b> 身B US-PGPUB; EPO; JPO; DERWENT;	2004/09/11 22:01			0
52	BRS	11	mask\$ near side\$7 with sacrificial	也 <b>S坪A</b> 中 <b>D</b> B US-PGPUB; EPO; JPO; DERWENT;	2004/09/13 12:19			0
53	BRS	11	gate near stack\$ and mask\$ with sacrificial and high adj k		2004/09/13 12:20			0
54	BRS	11	gate near stack\$ and mask\$ with sacrificial and high adj k and metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 12:29		-	0
55	BRS	5	and masks with prespacer and high adj k and metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 12:32		70 WATER 1999 W	0
56	BRS	5	gate near stack\$ and mask\$ with prespacer and metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 12:33			0
57	BRS	15	gate near stack\$ and mask\$ with (sacrificial or prespacer) and gate near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 14:18		the fact of the fa	0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e n	D e f	Ennons
58	BRS	3	•	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 12:47			0
59	BRS	10 8	mask\$ with (sacrificial or prespacer) and gate near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 12:48			0
60	BRS	14	mask\$ with (sacrificial or prespacer) and gate near metal and high adj k	JPO; DERWENT; IBM_TDB	2004/09/13 13:49			0
61	BRS	3	mask\$ near metal and gate near metal and high adj k and work adj function	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 13:53			0
62	BRS	30	l .	JPO; DERWENT; IBM_TDB	2004/09/13 13:54			0
63	BRS	19	gate near stack\$ and mask\$ with (sacrificial or prespacer or liner or lining) and gate near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 14:19			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	o m m e n t s	e f	Errors
1	BRS	1	near mask\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:17			0
2	BRS	:	high adj K with metal and metal with mask\$ and mask\$ with sacrificial	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:20			0
3	BRS	11	high adj K with metal and metal with mask\$ and mask\$ with sidewall with spacer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:20			0
4	BRS	16	high adj K with metal and metal with mask\$ and conformal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:29			0
5	BRS	39		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:38			0
6	BRS	91	dielectric with metal and metal with mask\$ and wet near etch\$ with dielectric and (dry or plasma) near etch\$ with metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/10 18:55			0
7	BRS	6	6300202.URPN.	$      \subseteq D \cap D$	2004/09/10 18:48			0
8	BRS	2	("5885877"   "6300202").PN.		2004/09/10 18:50			0
9	BRS	30	5885877.URPN.	USPAT	2004/09/10 18:50			0

	Тур е	Hi ts	Search Text	DBs	Time	Stamp	m m e n	D e f	Error
10	BRS		with (high near K near dielectric or metal near	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 19:00	09/10			0
11	BRS		protect\$ or	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 17:51	09/11			0
12	BRS	10		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 17:57	09/11			0
13	BRS	2	high near k with dielectric with metal and mask\$ near metal and sidewall with (spacer or protect\$) with mask\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 18:00				0

	Тур	Hi ts	Search Text	DBs	Time	Stamp	m e n	Enror
14	BRS		l .	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 18:06	09/11		0
15	BRS	32	etch\$ with metal with stack and sidewall with (spacer or protect\$) with mask\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 18:17			0
16	BRS	4	mask\$ near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 18:21	09/11		О
17	BRS	0.6		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 18:24			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e n t	ErrorDefinitio	r r o r
18	BRS	24	(dielectric or oxide) with substrate and metal with (dielectric or oxide) and mask\$ with metal and (sidewall or spacer or protect\$) with mask\$ and high adj k and mask\$ with polysilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:38			0
19	BRS	12	(dielectric or oxide) with substrate and metal with (dielectric or oxide) and mask\$ with metal and side\$6 with mask\$ and high adj k and mask\$ with polysilicon and gate near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 18:43			0
20	BRS	45	gate near metal and mask\$ with metal and (cap\$6 or protect\$ or sacrificial) with mask\$ with side\$6 and mask\$ with polysilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 19:21			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	e n	e f	н н о н
21	BRS	2	gate near metal and mask\$ near (metal or gate) and high adj k with gate near dielectric and (cap\$6 or protect\$ or sacrificial) with mask\$ with side\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 19:25			О
22	BRS	3	gate near metal and high adj k with gate near dielectric and (cap\$6 or protect\$ or sacrificial) with mask\$ with side\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 19:26	A NAMES AND ADDRESS AND ADDRES		0
23	BRS	34	gate near metal and high adj k with gate near dielectric and mask\$ with side\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 20:36	A STATE OF THE PARTY OF THE PAR		0
24	BRS	59	gate near metal and high adj k with gate near dielectric and mask\$ and work adj function	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:05			0
25	BRS	6	gate near metal and gate near dielectric and mask\$ near (metal or gate) and work adj function and (protect\$ or sacrificial or conformal) with metal with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:13	eri main man meni ikun man untiman manamini interintentifika kenya mahi sana mahi ikun ikin ikin mini mahi a		0

	Тур е	Hi ts	Search Text	DBs	Time Stam	n P e r	r r f f	Errors
26	BRS			USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:20			0
27	BRS		etch\$ with gate near metal same mask\$ near (metal or gate) and work adj function and layer with (metal or gate) with	DIO, OLO,	2004/09/11 21:27			0
28	BRS	11	machs with gate near metal and mask\$ near (metal or gate) and work adj function and layer with (metal or gate) with	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:28			0
29	BRS	1	######################################	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:39			0
30	BRS		Tunction and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:32			0

	Тур е	Hi ts	Search Text	DBs	Time Stamp	m m e n	ErrorDefinitio	
39	IS& R	2	("6420279").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:53			0
40	IS& R	2	("6475874").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:54			0
41	IS& R	2	("6514828").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:54			0
42	IS& R	2	("6544906").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:54			0
43	IS& R	2	("6617209").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:55			0
44	IS& R	2	("6620713").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:55			0
45	IS& R	2	("6689675").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:56			0
46	IS& R	2	("6696345").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:57			0
47	IS& R	2	("6696327").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:57			0
48	IS& R	0	(2002/0197790).CC LS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 22:00			0
49	IS& R	2	("20020197790").P N.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 22:01			0
50	IS& R	2	("20030032303").P N.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 22:01			0
51	IS& R	2	("20030045080").P N.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 22:01			0

	Тур е	Hi ts	Search Text	DBs		Stamp	o m m e n t s	ErrorDefinitio	Enron
52	BRS	11	with sacrificial	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:19	09/13			0
53	BRS	11	gate near stack\$ and mask\$ with sacrificial and high adj k	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:20	09/13			0
54	BRS		sacrificial and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:29	09/13			0
55	BRS	5	gate near stack\$ and mask\$ with prespacer and high adj k and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:32	09/13			0
56	BRS		मुश्चिंचे near stack and mask\$ with prespacer and metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:33	09/13			0
57	BRS	15	gate near stack\$ and mask\$ with (sacrificial or prespacer) and gate near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 14:18	09/13			0
58	BRS	3	gate near stack\$ and mask\$ with (sacrificial or prespacer) and gate near metal and high adj k	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:47	09/13			0
59	BRS	10 8	mask\$ with (sacrificial or prespacer) and gate near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 12:48	09/13			0
60	BRS	14	mask\$ with (sacrificial or prespacer) and gate near metal and high adj k	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/ 13:49	09/13			0

	Тур e	Hi	Search Text	DBs	Time Stamp	m m e	f	E r r
61	BRS		incour and magn	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 13:53		:	0
62	BRS	30	troub adi funation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 13:54	4		0
63	BRS	19	nragnagar ar	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 14:19			0

	Тур	Hi ts	Search Text	DBs	Time Stamp	m m e n	r D	E r r o r s
31	BRS	O	1 -	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:33			0
32	BRS	17		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:34			0
33	BRS	1	etch\$ with gate same mask\$ near gate and sacrificial with metal with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:41			0
34	BRS	2	etch\$ and gate near stack\$ same mask\$ near gate and sacrificial with gate with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:45			0
35	BRS	1	etch\$ near gate same mask\$ near gate and work adj function and sacrificial with gate with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:47			0
36	BRS	3	etch\$ near gate same mask\$ near gate and sacrificial with gate with mask	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 22:10			0
37	IS& R	2	("6063698").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:52			0
38	IS& R	2	("6184072").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/11 21:53			0